

Description

The AP30P03D uses advanced trench technology to provide excellent $R_{\text{DS}(\text{ON})}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a

Battery protection or in other Switching application.

 $V_{DS} = -30V I_{D} = -30 A$

General Features

 $R_{DS(ON)} < 20m\Omega$ @ $V_{GS}=10V$

Application

Battery protection

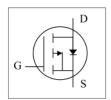
Load switch

Uninterruptible power supply



Product ID	Pack	Marking	Qty(PCS)
AP30P03D	TO-252-3L	AP30P03D XXXX YYYY	2500

		Ra			
Symbol	Parameter	10s	Steady State	Units	
V _{DS}	Drain-Source Voltage	-	-30		
Vgs	Gate-Source Voltage	±	±20		
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ -10V ¹	-	-30	Α	
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ -10V ¹	-22		Α	
I _D @T _A =25°C	Continuous Drain Current, V _{GS} @ -10V ¹	-13.4 -8.5		Α	
I _D @T _A =70°C	Continuous Drain Current, V _{GS} @ -10V ¹ -10.7		-6.8	Α	
Ірм	Pulsed Drain Current ²	-70		Α	
EAS	Single Pulse Avalanche Energy ³	72.2		mJ	
IAS	Avalanche Current	-38		Α	
P _D @T _C =25°C	Total Power Dissipation ⁴	34.7		W	
P _D @T _A =25°C	Total Power Dissipation ⁴	n ⁴ 5 2		W	
Тѕтс	Storage Temperature Range -55 to 150		to 150	°C	
TJ	Operating Junction Temperature Range	-55 to 150		°C	
ReJA	Thermal Resistance Junction-Ambient ¹ 62		°C/W		
Reja	Thermal Resistance Junction-Ambient ¹ (t ≤10s)	25		°C/W	
Rejc	Thermal Resistance Junction-Case ¹	3.6		°C/W	











Electrical Characteristics (T $_J$ =25 $^{\circ}$ C, unless otherwise noted)

Symbol	I Parameter Conditions			Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =-250uA	-30			V
△BVpss/△TJ	BV _{DSS} Temperature Coefficient	Reference to 25°C , I _D =-1mA		-0.022		V/°C
		V _{GS} =-10V , I _D =-15A		18	20	
RDS(ON)	Static Drain-Source On-Resistance ²	V _{GS} =-4.5V , I _D =-10A		25	32	$\mathbf{m}\Omega$
$V_{GS(th)}$	Gate Threshold Voltage		-1.0		-2.5	V
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	V _{GS} =V _{DS} , I _D =-250uA		4.6		mV/°C
		V _{DS} =-24V , V _{GS} =0V , T _J =25°C			-1	
IDSS	Drain-Source Leakage Current	V _{DS} =-24V , V _{GS} =0V , T _J =55°C			-5	uA
Igss	Gate-Source Leakage Current	V_{GS} = $\pm 20V$, V_{DS} = $0V$			±100	nA
gfs	Forward Transconductance	V _{DS} =-5V , I _D =-10A		5		S
Rg	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		13		Ω
Qg	Total Gate Charge (-4.5V)			12.5		
Qgs	Gate-Source Charge	V _{DS} =-15V , V _{GS} =-4.5V , I _D =-15A		5.4		nC
Qgd	Gate-Drain Charge			5		
Td(on)	Turn-On Delay Time			4.4		
Tr	Rise Time	V _{DD} =-15V , V _{GS} =-10V ,		11.2		
Td(off)	Turn-Off Delay Time	—R _G =3.3 ,		34		ns
T _f	Fall Time	I _D =-15A		18		
Ciss	Input Capacitance			1345		
Coss	Output Capacitance	 V _{DS} =-15V , V _{GS} =0V , f=1MHz		194		pF
Crss	Reverse Transfer Capacitance			158		
ls	Continuous Source Current ^{1,5}				-35	Α
Ism	Pulsed Source Current ^{2,5}	−V _G =V _D =0V , Force Current			-70	Α
VsD	Diode Forward Voltage ²	V _{GS} =0V , I _S =-1A , T _J =25°C			-1.2	V
t _{rr}	Reverse Recovery Time	I=-15A , dI/dt=100A/μs ,		12.4		nS
Qrr	Reverse Recovery Charge	T _J =25°C		5		nC



Typical Characteristics

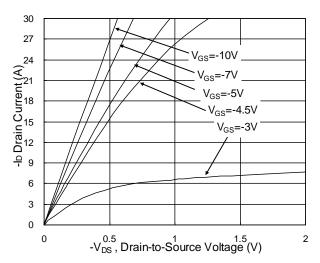


Fig.1 Typical Output Characteristics

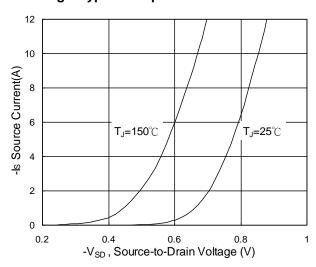


Fig.3 Forward Characteristics of Reverse

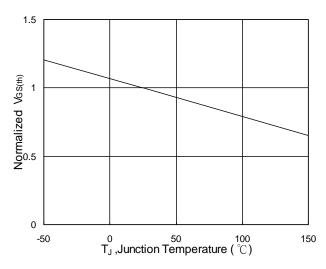


Fig.5 Normalized V_{GS(th)} v.s T_J

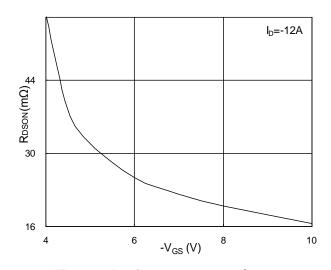


Fig.2 On-Resistance v.s Gate-Source

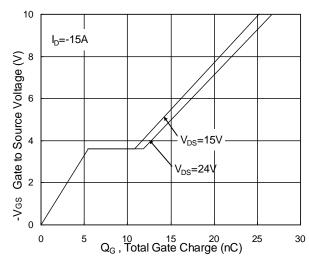


Fig.4 Gate-Charge Characteristics

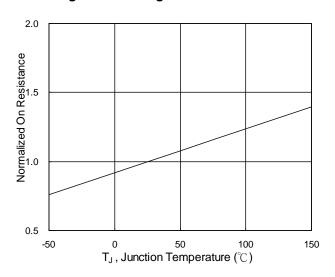
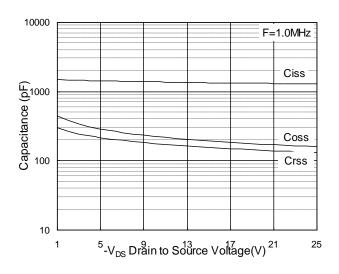


Fig.6 Normalized R_{DSON} v.s T_J







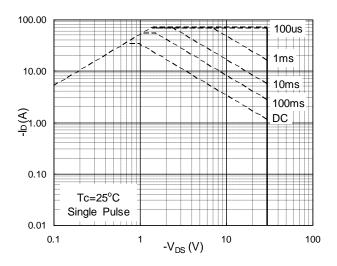


Fig.7 Capacitance

Fig.8 Safe Operating Area

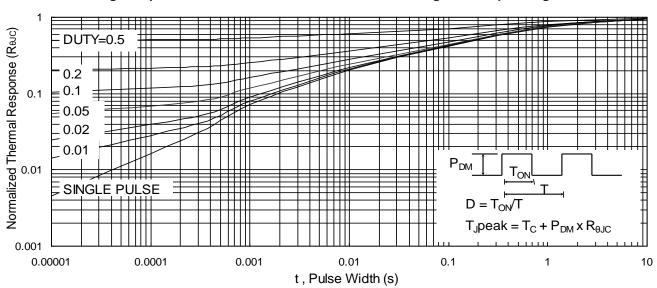


Fig.9 Normalized Maximum Transient Thermal Impedance

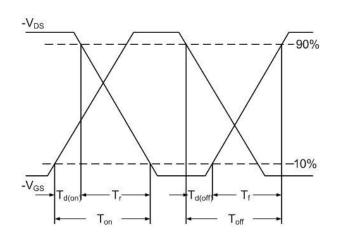


Fig.10 Switching Time Waveform

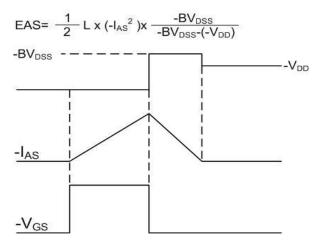
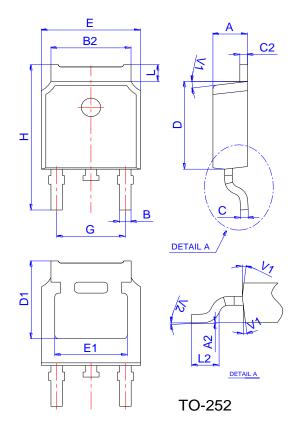


Fig.11 Unclamped Inductive Switching Waveform

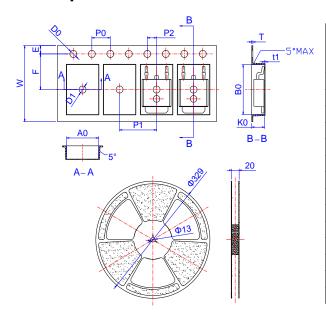


Package Mechanical Data



	Dimensions					
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
В	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
С	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1		5.30REF		0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
Н	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

Reel Spectification-TO-252



	Dimensions						
Ref.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
W	15.90	16.00	16.10	0.626	0.630	0.634	
E	1.65	1.75	1.85	0.065	0.069	0.073	
F	7.40	7.50	7.60	0.291	0.295	0.299	
D0	1.40	1.50	1.60	0.055	0.059	0.063	
D1	1.40	1.50	1.60	0.055	0.059	0.063	
P0	3.90	4.00	4.10	0.154	0.157	0.161	
P1	7.90	8.00	8.10	0.311	0.315	0.319	
P2	1.90	2.00	2.10	0.075	0.079	0.083	
A0	6.85	6.90	7.00	0.270	0.271	0.276	
В0	10.45	10.50	10.60	0.411	0.413	0.417	
K0	2.68	2.78	2.88	0.105	0.109	0.113	
Т	0.24		0.27	0.009		0.011	
t1	0.10			0.004			
10P0	39.80	40.00	40.20	1.567	1.575	1.583	



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